NSN 5961-00-103-3952

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Inclosure Material:

Metal

Overall Length:

Between 0.250 inches and 0.450 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

140.0 breakdown voltage, collector-to-base, emitter open and 120.0 breakdown voltage, collector-to-emitter, base open and 7.00

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

10.00 amperes source cutoff current and 4.00 amperes base current, dc

Power Rating Per Characteristic:

120.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

1 case and 2 pin

Specification Data:

80131-release-5357 professional/industrial association standard

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0